IN THE SPECIFICATION:

Page 1, lines 2-5:

Background of the Invention

The invention relates to a semiconductor structure with active zones, according to the preamble to Claim 1, and to a method for manufacturing such a semiconductor. The invention further relates to a blended-color sensor, and to a colored display that contains the semiconductor structure with the active zones.

Page 3, between lines 17 and 18, insert:

Summary of the Invention

Page 8, between lines 13 and 14, insert:

Brief Description of the Drawings

Page 10, above line 1, insert:

Description of the Preferred Embodiments